

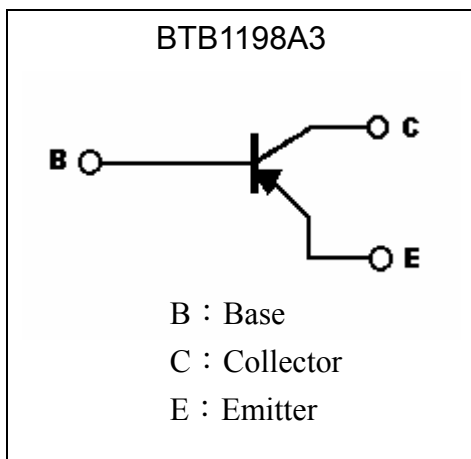
PNP Epitaxial Planar Transistor

BTB1198A3

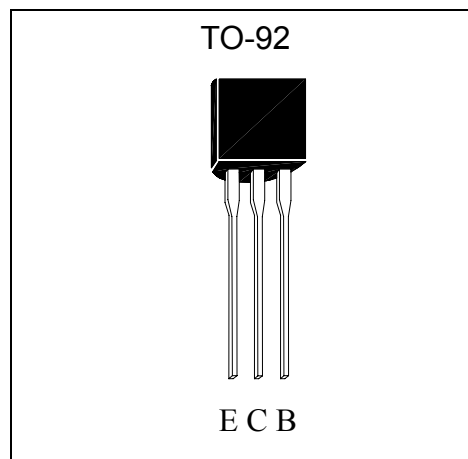
Features

- Low $V_{CE(SAT)}$, $V_{CE(SAT)} = -0.16V$ (Typ.) @ $I_C/I_B = -500mA/-50mA$
- High breakdown voltage, $BV_{CEO} = -80V$
- Complementary to BTB1768A3
- Pb-free lead plating and halogen-free package

Symbol



Outline



Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-Base Voltage	V_{CBO}	-80	V
Collector-Emitter Voltage	V_{CEO}	-80	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current (DC)	I_C	-1	A
Collector Current (Pulse)	I_{CP}	-2 (Note)	A
Power Dissipation	P_D	750	mW
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	167	°C/W
Operating Junction Temperature Range	T_j	-55~+150	°C
Storage Temperature Range	T_{stg}	-55~+150	°C

Note : Pulse test, $P_w \leq 10ms$, Duty $\leq 50\%$.

**Characteristics** (Ta=25°C)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
BV _{CBO}	-80	-	-	V	I _C =-50μA
BV _{CEO}	-80	-	-	V	I _C =-2mA
BV _{EBO}	-5	-	-	V	I _E =-50μA
I _{CBO}	-	-	-0.5	μA	V _{CB} =-50V
I _{EBO}	-	-	-0.5	μA	V _{EB} =-4V
*V _{CE(sat)}	-	-0.16	-0.5	V	I _C =-500mA, I _B =-50mA
*h _{FE}	120	-	560	-	V _{CE} =-3V, I _C =-100mA
f _T	-	180	-	MHz	V _{CE} =-10V, I _C =-50mA, f=100MHz
Cob	-	11	-	pF	V _{CB} =-10V, f=1MHz

*Pulse Test: Pulse Width ≤380μs, Duty Cycle≤2%

Classification Of h_{FE}

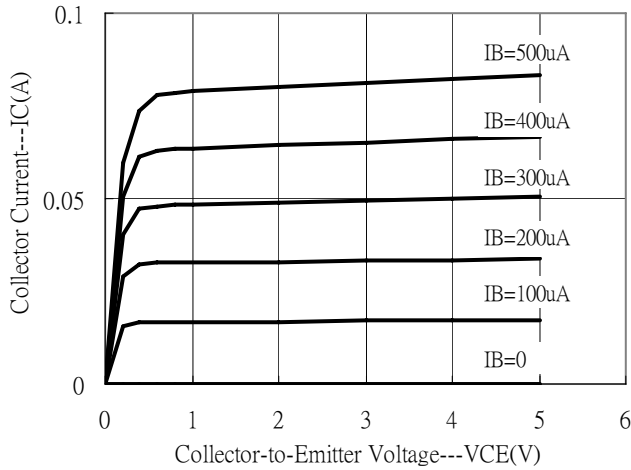
Rank	Q	R	S
Range	120~270	180~390	270~560

Ordering Information

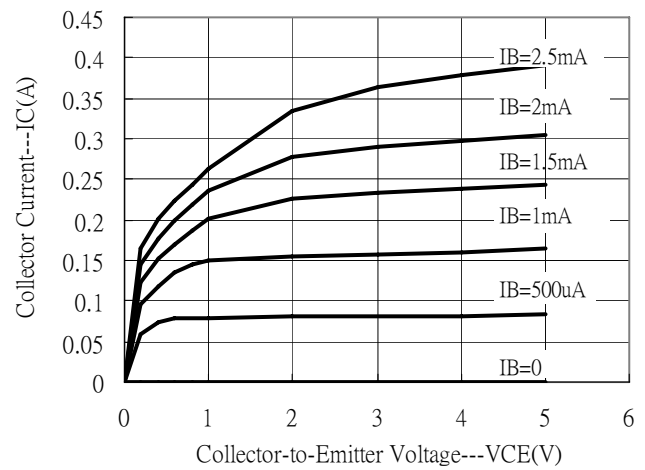
Device	HFE rank	Package	Shipping
BTB1198A3-Q-BK-G	Q	TO-92 (Pb-free lead plating and halogen-free package)	1000 pcs/ bag, 10 bags/box, 10boxes/carton
BTB1198A3-R-BK-G	R	TO-92 (Pb-free lead plating and halogen-free package)	1000 pcs/ bag, 10 bags/box, 10boxes/carton
BTB1198A3-S-BK-G	S	TO-92 (Pb-free lead plating and halogen-free package)	1000 pcs/ bag, 10 bags/box, 10boxes/carton
BTB1198A3-Q-TB-G	Q	TO-92 (Pb-free lead plating and halogen-free package)	2000 pcs / Tape & Box
BTB1198A3-R-TB-G	R	TO-92 (Pb-free lead plating and halogen-free package)	2000 pcs / Tape & Box
BTB1198A3-S-TB-G	S	TO-92 (Pb-free lead plating and halogen-free package)	2000 pcs / Tape & Box

Characteristic Curves

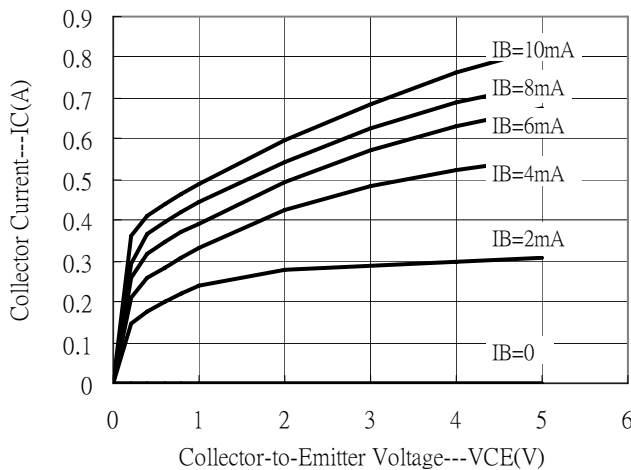
Output Characteristics



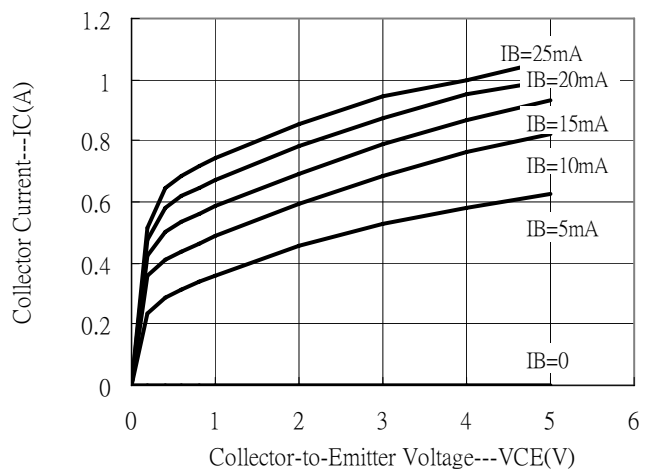
Output Characteristics



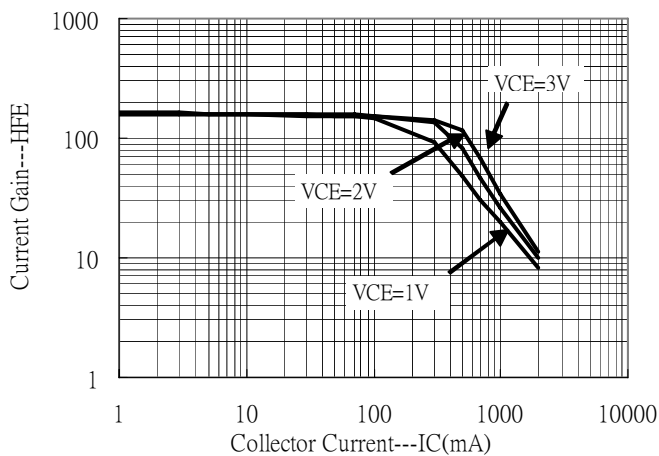
Output Characteristics



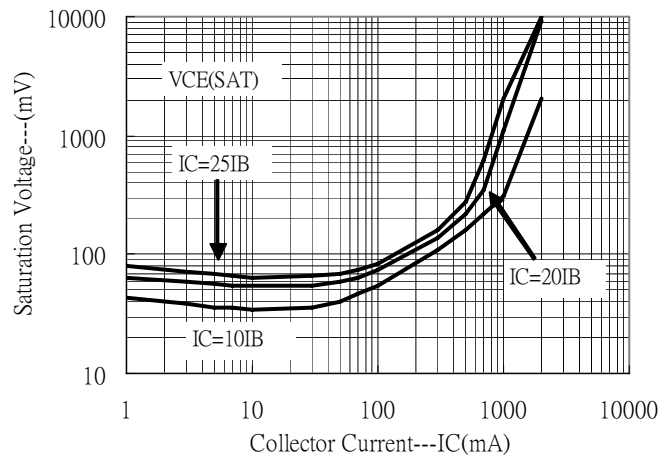
Output Characteristics



Current Gain vs Collector Current

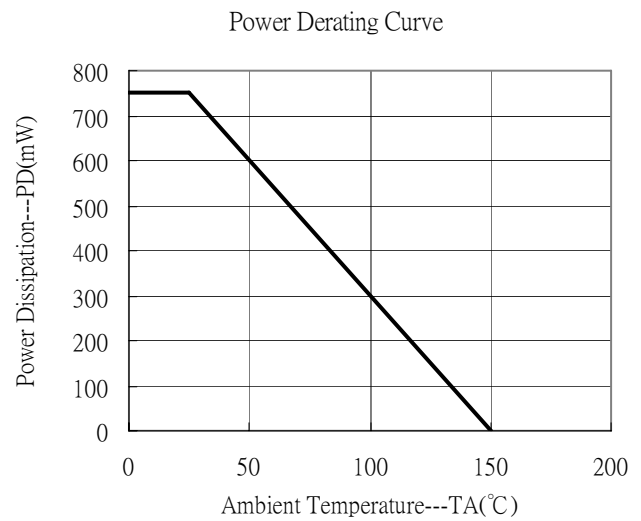
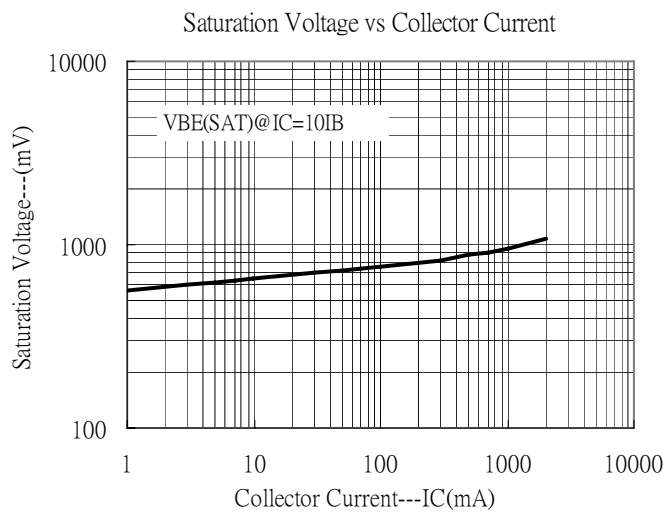


Saturation Voltage vs Collector Current

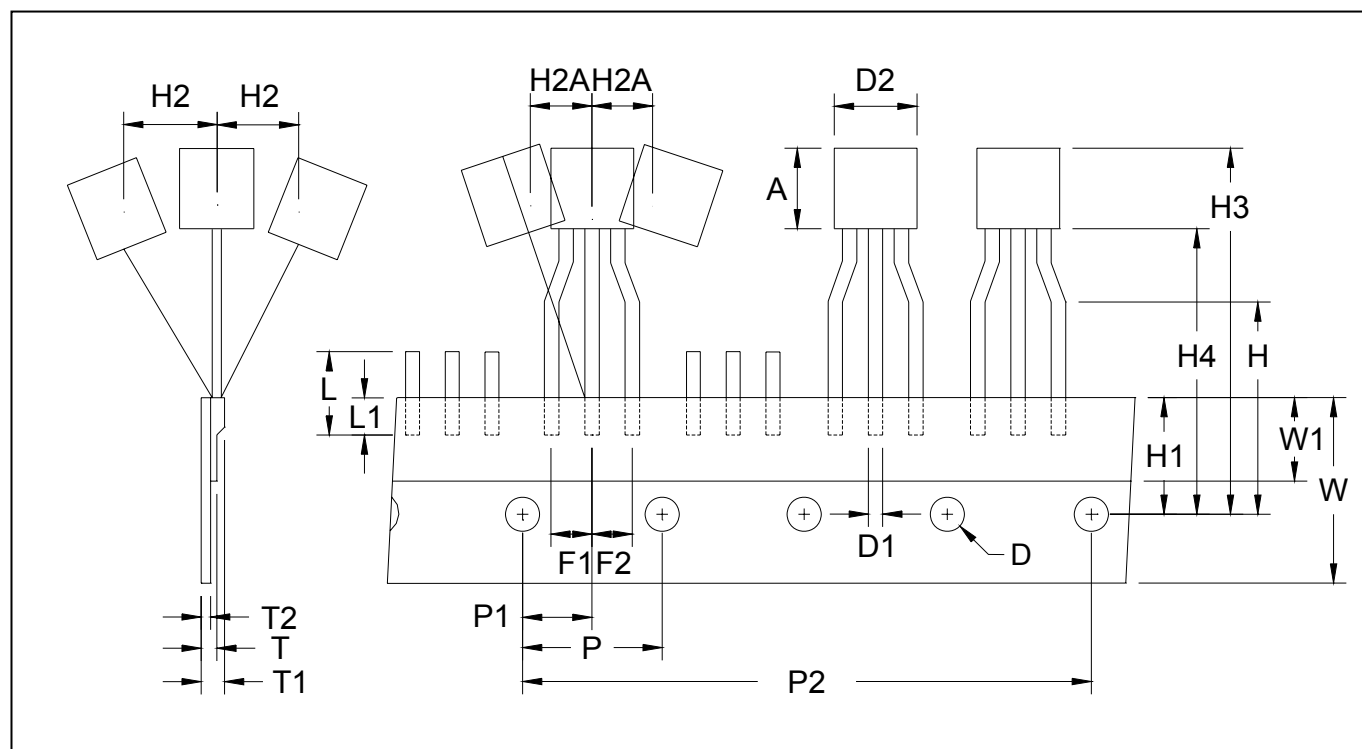




Characteristic Curves(Cont.)



TO-92 Taping Outline

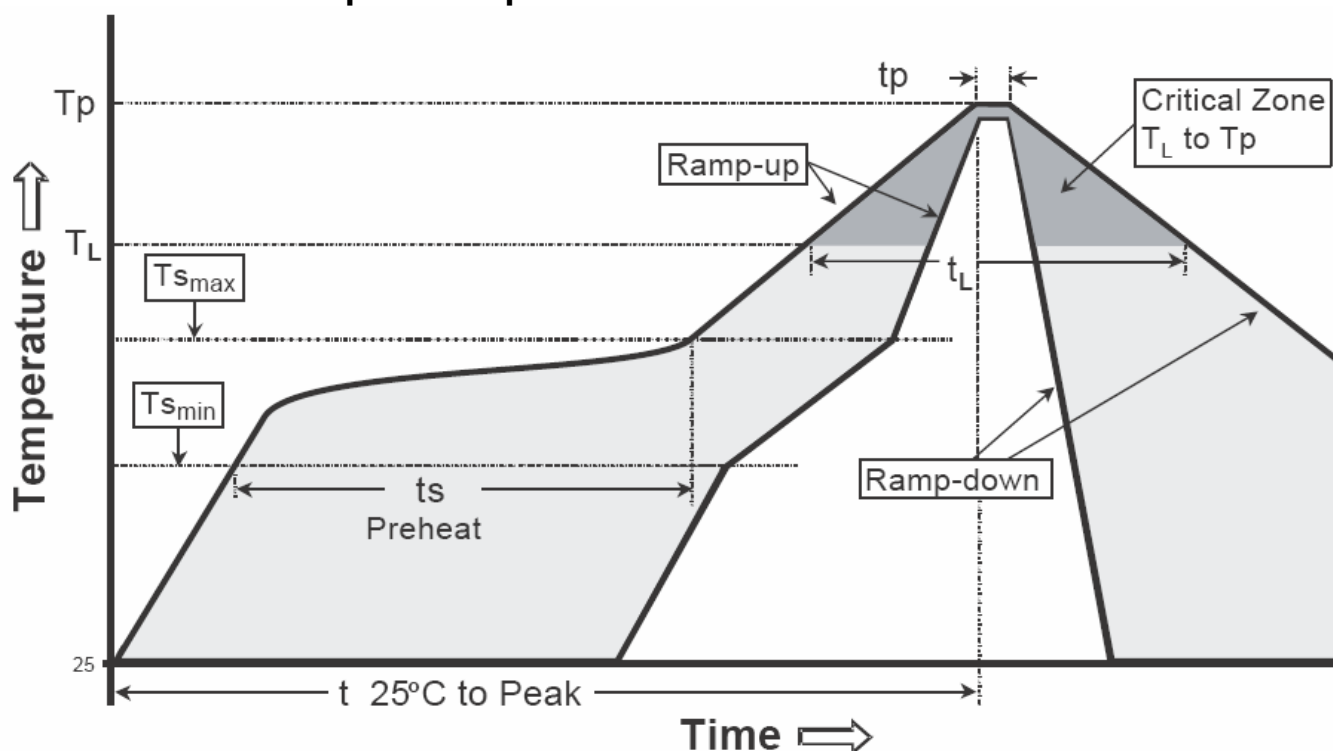


DIM	Item	Millimeters	
		Min.	Max.
A	Component body height	4.33	4.83
D	Tape Feed Diameter	3.80	4.20
D1	Lead Diameter	0.36	0.53
D2	Component Body Diameter	4.33	4.83
F1,F2	Component Lead Pitch	2.40	2.90
F1,F2	F1-F2	-	±0.3
H	Height Of Seating Plane	15.50	16.50
H1	Feed Hole Location	8.50	9.50
H2	Front To Rear Deflection	-	1
H2A	Deflection Left Or Right	-	1
H3	Component Height	-	27
H4	Feed Hole To Bottom Of Component	-	21
L	Lead Length After Component Removal	-	11
L1	Lead Wire Enclosure	2.50	-
P	Feed Hole Pitch	12.50	12.90
P1	Center Of Seating Plane Location	5.95	6.75
P2	4 Feed Hole Pitch	50.30	51.30
T	Over All Tape Thickness	-	0.55
T1	Total Taped Package Thickness	-	1.42
T2	Carrier Tape Thickness	0.36	0.68
W	Tape Width	17.50	19.00
W1	Adhesive Tape Width	5.00	7.00
-	20 pcs Pitch	253	255

Recommended wave soldering condition

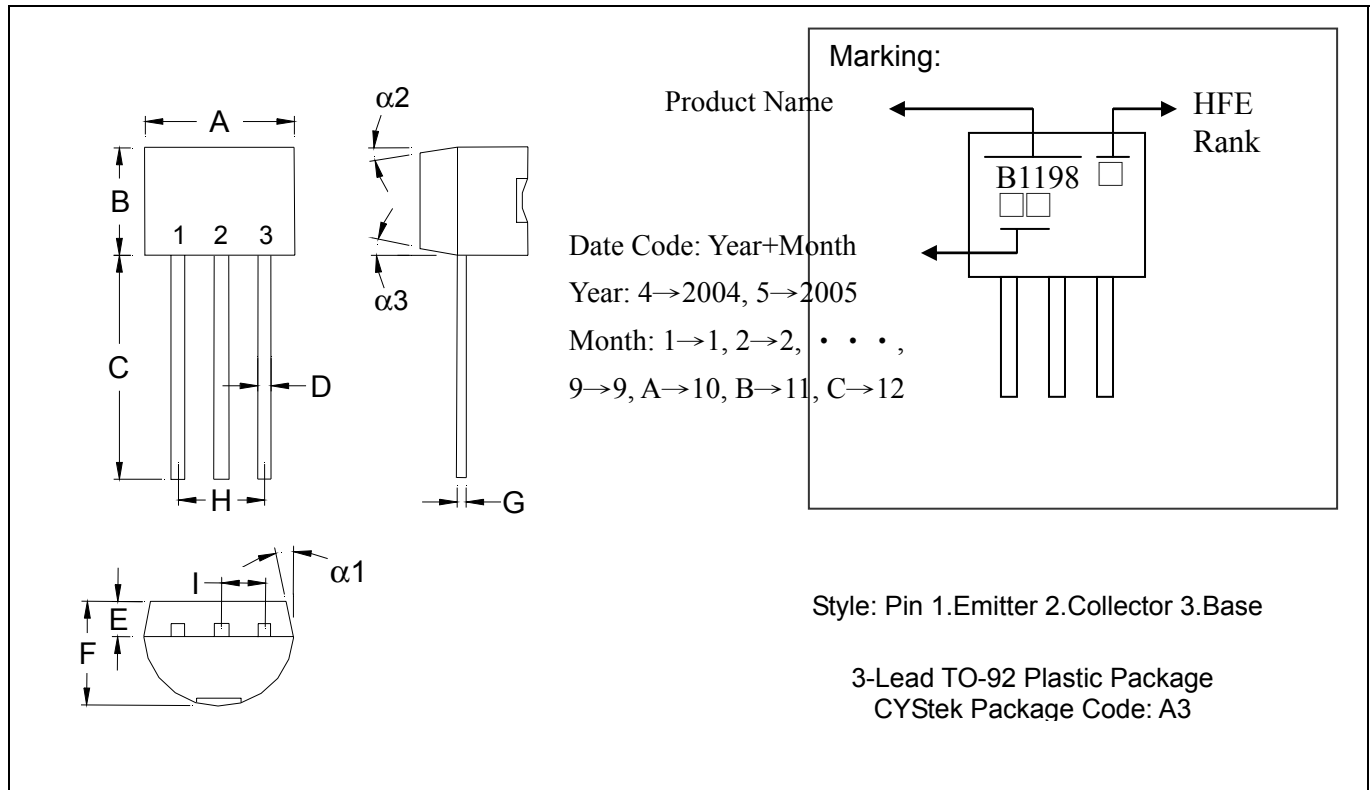
Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (T_{smax} to T_p)	3°C/second max.	3°C/second max.
Preheat		
-Temperature Min(T_{smin})	100°C	150°C
-Temperature Max(T_{smax})	150°C	200°C
-Time(t_{smin} to t_{smax})	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (T_L)	183°C	217°C
- Time (t_L)	60-150 seconds	60-150 seconds
Peak Temperature(T_p)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(t_p)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

TO-92 Dimension



*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1704	0.1902	4.33	4.83	G	0.0142	0.0220	0.36	0.56
B	0.1704	0.1902	4.33	4.83	H	-	*0.1000	-	*2.54
C	0.5000	-	12.70	-	I	-	*0.0500	-	*1.27
D	0.0142	0.0220	0.36	0.56	$\alpha 1$	-	*5°	-	*5°
E	-	*0.0500	-	*1.27	$\alpha 2$	-	*2°	-	*2°
F	0.1323	0.1480	3.36	3.76	$\alpha 3$	-	*2°	-	*2°

Notes: 1. Controlling dimension: millimeters.

2. Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.

3. If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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